


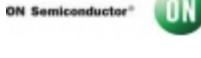






	<h2 style="color: red;">FQP13N50</h2>
	<p>Hersteller-Teilenummer: FQP13N50</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 12.5A TO-220</p> <p>Datenblätter: 1.FQP13N50.pdf 2.FQP13N50.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34951 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N50
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 500V 12.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34951 pcs Stock
Hersteller Standard Vorlaufzeit	5 Weeks
detaillierte Beschreibung	N-Channel 500V 12.5A (Tc) 170W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	170W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.5A (Tc)
Rds On (Max) @ Id, Vgs	430 mOhm @ 6.25A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2300pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP13N50 ist neu im Original, Suche FQP13N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N50 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N50: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N50C Fairchild/ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N50C_F105 AMI Semiconductor / ON Semiconductor IC POWER MANAGEMENT</p>	 <p>FQP13N50C AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N10C FSC FQP13N10C FSC</p>
 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>	 <p>FQP13N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>

heiße Teile

Mehr

⊗ FQP11N50CF	↔ FQP11N50CF	⇒ FQP11N60	D FQP11N60C	↕ FQP11N65C
⊥ FQP11P06	⊗ FQP11P06	D FQP12N20	⇒ FQP12N60	↕ FQP12N60
⊗ FQP12N60C	⊥ FQP12N60C	⊗ FQP12N65C	↔ FQP12P10	↕ FQP12P10
D FQP12P20	⊗ FQP12P20	⊥ FQP13N06	⊗ FQP13N06	↕ FQP13N06L
⇒ FQP13N06L	↔ FQP13N10	⊗ FQP13N10	⊥ FQP13N10L	↕ FQP13N10L
↔ FQP13N50	⇒ FQP13N50C	D FQP13N50C	⊗ FQP13N60C	⊥ FQP140N03
⊗ FQP140N03L	D FQP14N15	⇒ FQP14N15	↔ FQP14N30	↕ FQP14N30
⊥ FQP14N80	⊗ FQP14N80C	↔ FQP15N16	⇒ FQP15N30	↕ FQP15N50
⊗ FQP15N60	⊥ FQP15N65	⊗ FQP15N80	D FQP15P12	↕ FQP15P12
↔ FQP16N15	⊗ FQP16N15	⊥ FQP16N25	⊗ FQP16N25	↕ FQP16N25C

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